absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Non-repetitive peak on-state pulse current (see Notes 1, 2 and 3)			
8/20 µs (ANSI C62.41, open-circuit voltage wave shape 1.2/50 µs)		150	
10/160 µs (FCC Part 68, open-circuit voltage wave shape 10/160 µs)		60	
5/200 µs (VDE 0433, open-circuit voltage wave shape 2 kV, 10/700 µs)		50	
0.2/310 µs (RLM 88, open-circuit voltage wave shape 1.5 kV, 0.5/700 µs)	I_{TSP}	38	A
5/310 µs (CCITT IX K17/K20, open-circuit voltage wave shape 2 kV, 10/700 µs)		50	
5/310 µs (FTZ R12, open-circuit voltage wave shape 2 kV, 10/700 µs)		50	
10/560 µs (FCC Part 68, open-circuit voltage wave shape 10/560 µs)		45	
10/1000 µs (REA PE-60, open-circuit voltage wave shape 10/1000 µs)		50	
Non-repetitive peak on-state current, 50 Hz, 2.5 s (see Notes 1 and 2)	I_{TSM}	10	A rms
Initial rate of rise of on-state current, Linear current ramp, Maximum ramp value < 38 A	di_T/dt	250	A/µs
Junction temperature	T_J	150	°C
Operating free - air temperature range		0 to 70	°C
Storage temperature range	T_{stg}	-40 to +150	°C
Lead temperature 1.5 mm from case for 10 s	T_{lead}	260	°C

NOTES: 1. Above 70°C, derate linearly to zero at 150°C case temperature
2. This value applies when the initial case temperature is at (or below) 70°C. The surge may be repeated after the device has returned to thermal equilibrium.
3. Most PTT's quote an unloaded voltage waveform. In operation the TISP essentially shorts the generator output. The resulting loaded current waveform is specified.

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electrical characteristics, T_J = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_Z	Reference zener voltage	I_Z = ± 1mA		± 145			V
$^{\propto}V_Z$	Temperature coefficient of reference voltage				0.1		%/°C
$V_{(BO)}$	Breakover voltage	(see Notes 4 and 5)				± 180	V
$I_{(BO)}$	Breakover current	(see Note 4)		± 0.15		± 0.6	A
V_{TM}	Peak on-state voltage	I_T = ± 5 A	(see Notes 4 and 5)		± 2.2	± 3	V
I_H	Holding current	(see Note 4)		± 150			mA
dv/dt	Critical rate of rise of off-state voltage	(see Note 6)				± 5	kV/µs
I_D	Off-state leakage current	V_D = ± 50 V				± 10	µA
C_{off}	Off-state capacitance	V_D = 0	f = 1 kHz		110	200	pF

NOTES: 4. These parameters must be measured using pulse techniques, t_w = 100 µs, duty cycle ≤ 2%.
5. These parameters are measured with voltage sensing contacts seperate from the current carrying contacts located within 3.2 mm (0.125 inch) from the device body.
6. Linear rate of rise, maximum voltage limited to 80 % V_Z (minimum).

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thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

PARAMETER MEASUREMENT INFORMATION

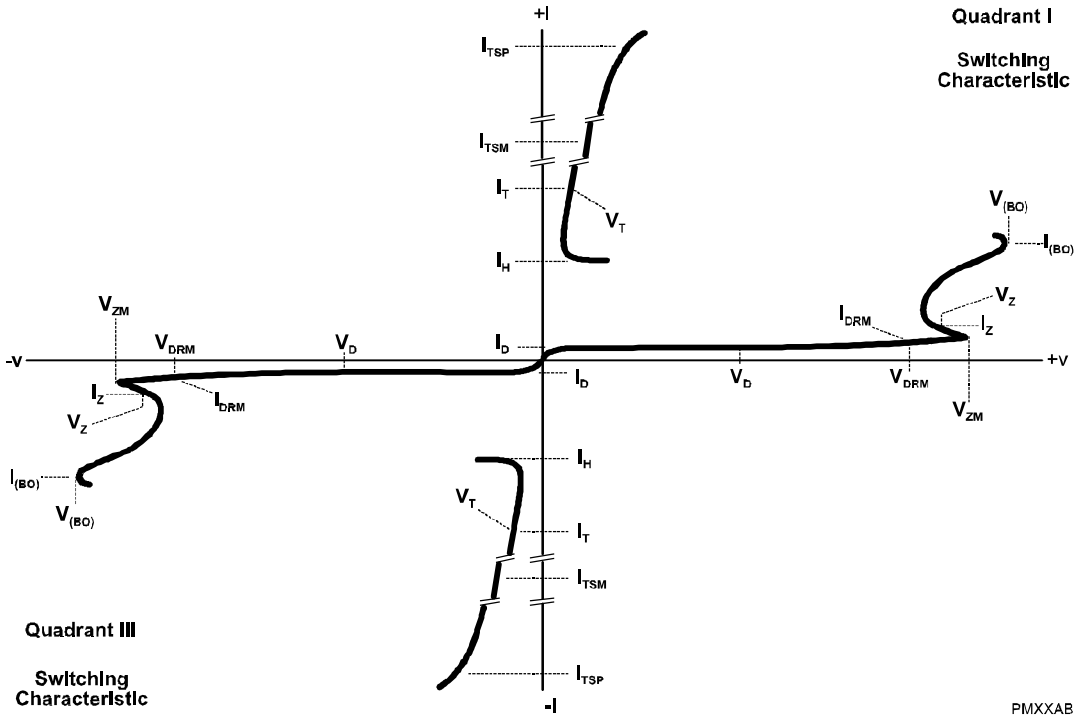


Figure 1. VOLTAGE-CURRENT CHARACTERISTIC FOR TERMINALS A and B

TYPICAL CHARACTERISTICS
A and B terminals

ON-STATE CURRENT vs ON-STATE VOLTAGE

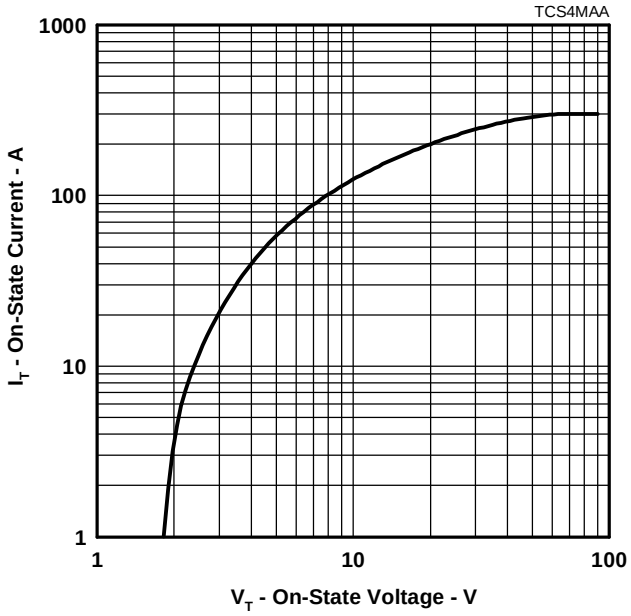


Figure 2.

ZENER VOLTAGE & BREAKOVER VOLTAGE vs JUNCTION TEMPERATURE

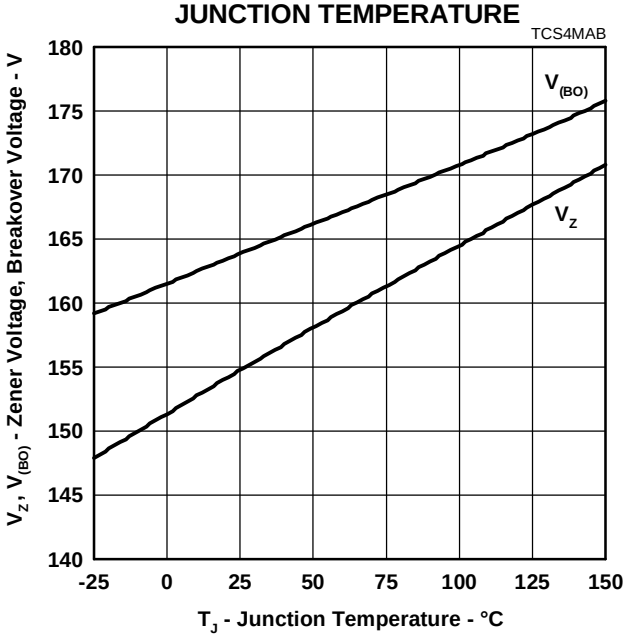


Figure 3.

TYPICAL CHARACTERISTICS
A and B terminals

HOLDING CURRENT & BREAKOVER CURRENT vs JUNCTION TEMPERATURE

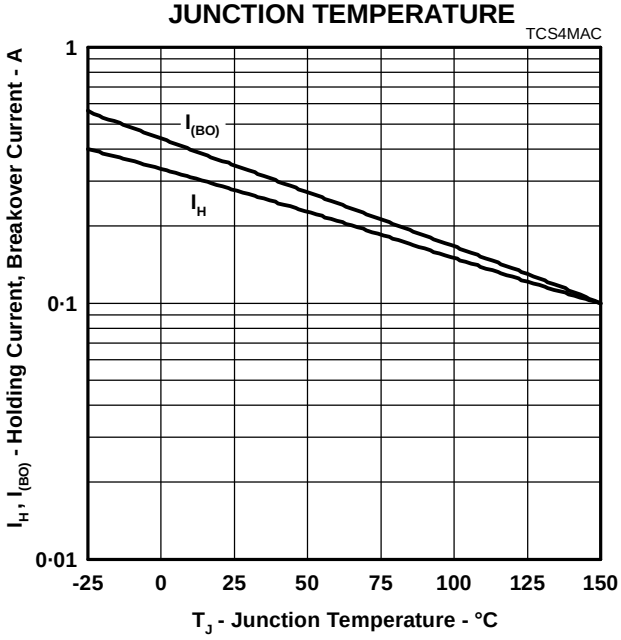


Figure 4.

OFF-STATE CURRENT vs JUNCTION TEMPERATURE

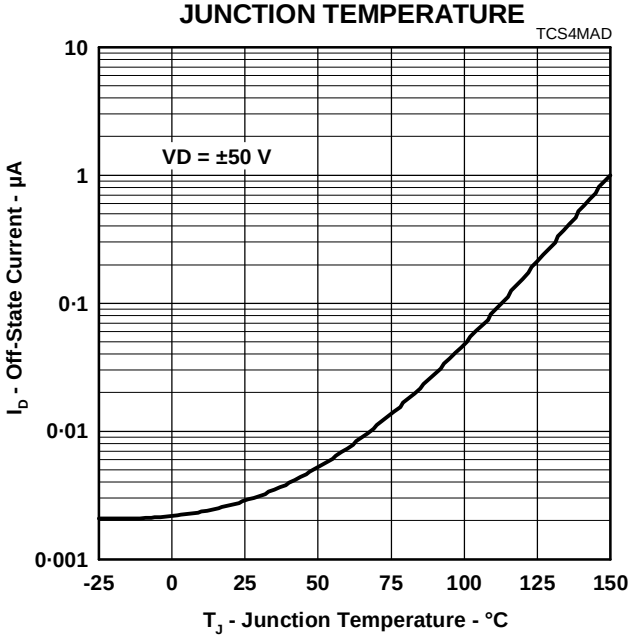


Figure 5.

ON-STATE VOLTAGE vs JUNCTION TEMPERATURE

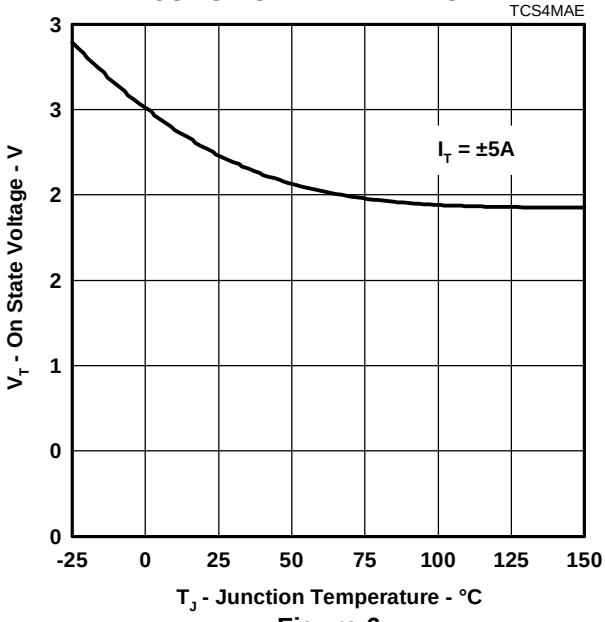


Figure 6.

NORMALISED BREAKOVER VOLTAGE vs RATE OF RISE OF PRINCIPLE CURRENT

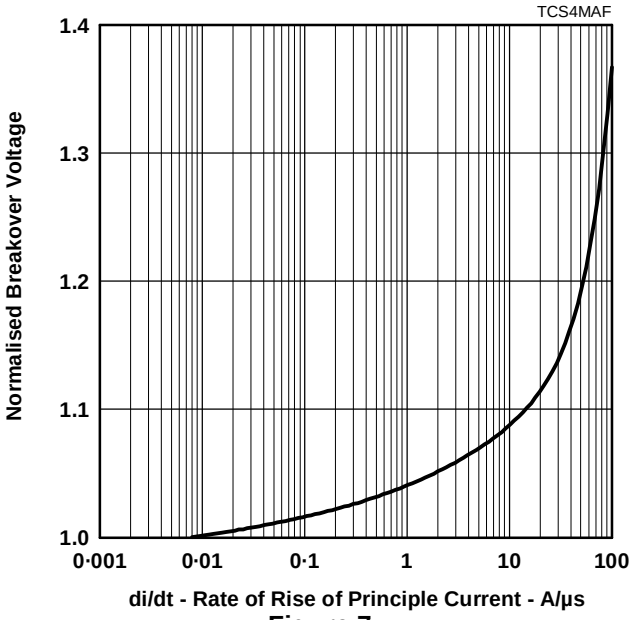


Figure 7.

TYPICAL CHARACTERISTICS
A and B terminals

OFF-STATE CAPACITANCE
vs
A TERMINAL VOLTAGE (POSITIVE)

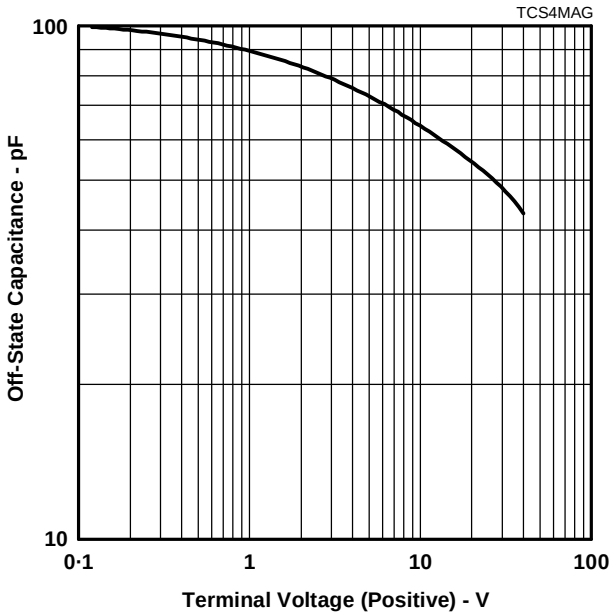


Figure 8.

OFF-STATE CAPACITANCE
vs
TERMINAL VOLTAGE (NEGATIVE)

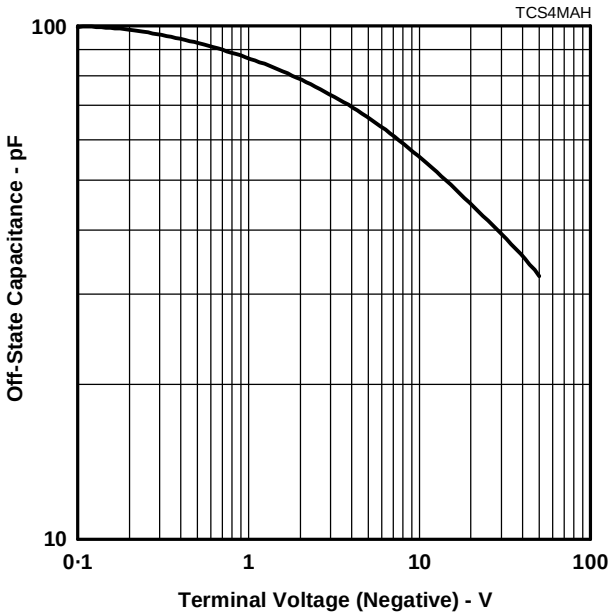


Figure 9.

SURGE CURRENT
vs
DECAY TIME

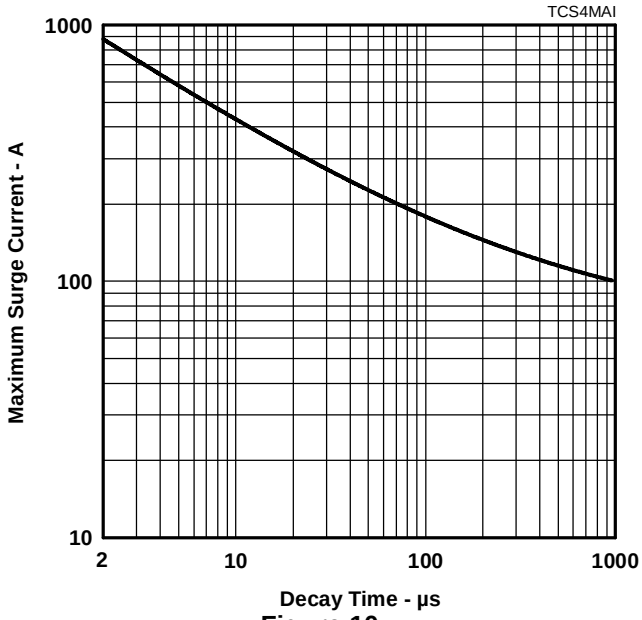


Figure 10.

THERMAL INFORMATION

THERMAL RESPONSE

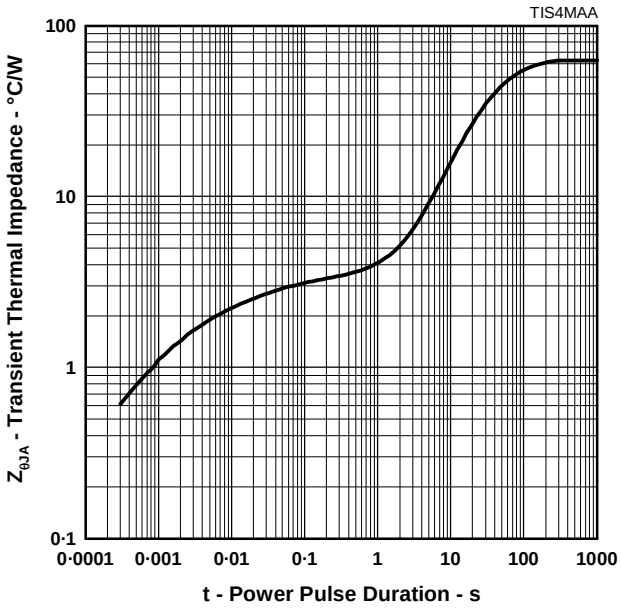


Figure 11.

MAXIMUM NON-RECURRENT 50 Hz CURRENT vs CURRENT DURATION

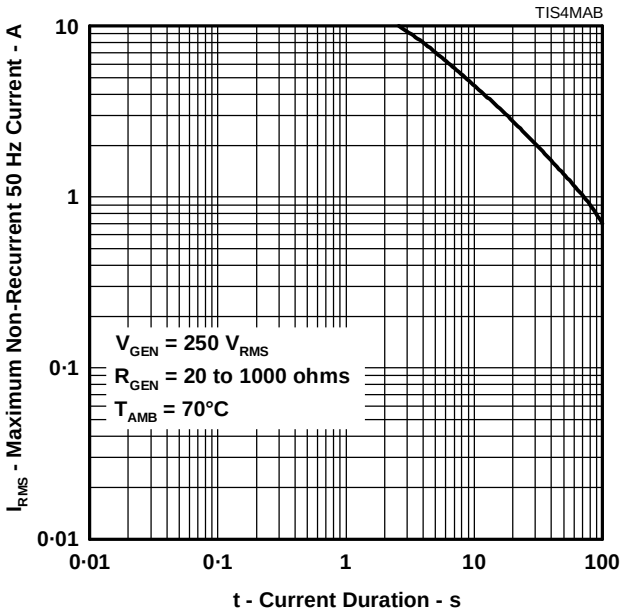


Figure 12.

FREE AIR TEMPERATURE DERATING CURVE

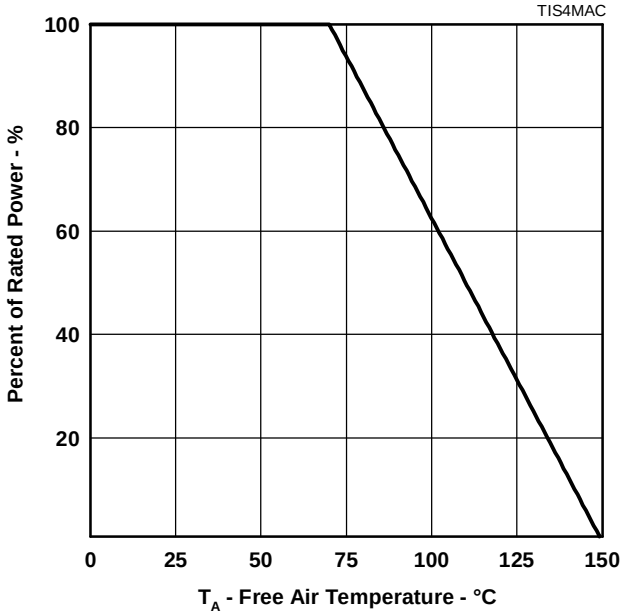


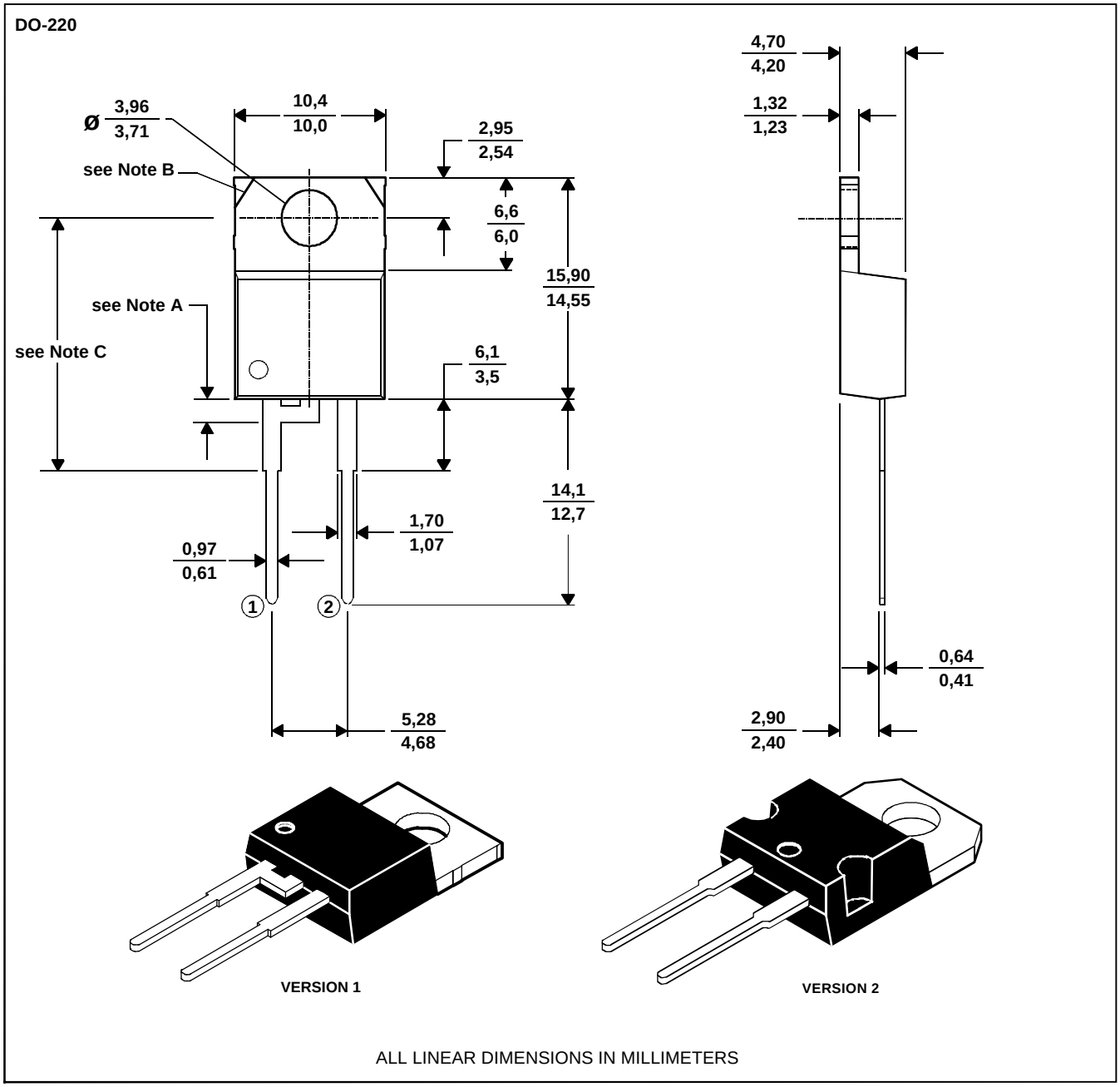
Figure 13.

MECHANICAL DATA

DO-220

2-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. Tie bar short stand off height according to package version.
Version 1, pin 1 is in electrical contact with the mounting tab via tie bar short - stand off height : 2,0 mm maximum.
Version 2, pin 1 is in electrical contact with the mounting tab (no external tie bar short).
B. Mounting tab corner profile according to package version.
C. Typical fixing hole centre stand off height according to package version.
Version 1, 18,0 mm. Version 2, 17,6 mm.

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